

DATASHEET

| Module TYPE | DDR2 2GB/1GB | | |
|----------------------|--------------|--|--|
| Wiodule 11PE | DIMM | | |
| Module speed | PC-6400 | | |
| CAS Latency | CL-6 | | |
| Pin | 240pin | | |
| SDRAM Operating Temp | 0 ℃ ~85 ℃ | | |

Total Solution For Industrial DRAM Module



1. Features

Key Parameter

| Industry | Speed | Data Rate MT/s | | | tRCD | tRP | tRC |
|--------------|-------|----------------|------|------|------|------|------|
| Nomenclature | Grade | CL=4 | CL=5 | CL=6 | (ns) | (ns) | (ns) |
| PC2-6400 | - | 533 | 667 | 800 | 15 | 15 | 60 |

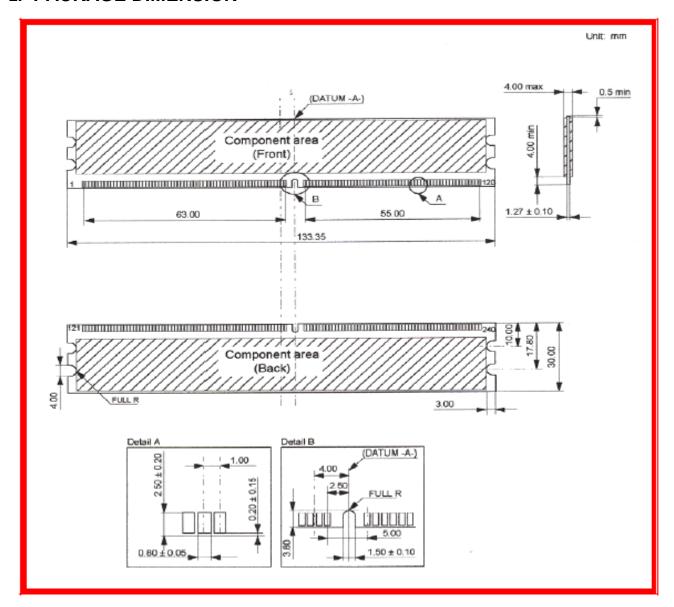
- JEDEC Standard 240-pin Dual In-Line Memory Module
- Intend for 400MHz applications
- Inputs and Outputs are SSTL-18 compatible
- VDD=VDDQ= 1.8 Volt \pm 0.1
- · Differential clock input
- All inputs are sampled at the positive going edge of the system clock
- Bi-Directional data strobe with one clock cycle preamble and one-half clock post-amble
- Address and control signals are fully synchronous to positive clock edge.
- Auto Refresh (CBR) and Self Refresh Modes support.
- Serial Presence Detect with EEPROM

- Automatic and controlled precharge commands.
- Auto & self refresh 7.8 μ s (TA \leq +85°C)
- Golden Contactor
- SDRAM Operation Temperature (Note 1)
 - $0^{\circ}C \leq TA \leq +85^{\circ}C$
- Programmable Device Operation:
 - Burst Type: Sequential or Inteleave
 - Operation: Burst Read and Write
 - Device CAS# Latency: 6
 - Burst Length: 4, 8
- RoHS Compliant (Section 15)

Note: 1. The refresh rate is required to double when Tc exceeds 85°C.



2. PACKAGE DIMENSION



Note: Device position is only for reference.